Unit: mm

TOSHIBA Transistor Silicon NPN Triple Diffused Type (PCT process)

2SC5353

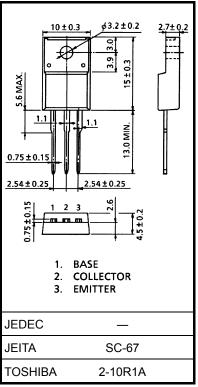
Switching Regulator and High Voltage Switching Applications

High-Speed DC-DC Converter Applications

- Excellent switching times: $t_r = 0.7 \mu s$ (max), $t_f = 0.5 \mu s$ (max)
- High collectors breakdown voltage: $V_{CEO} = 800 \text{ V}$

Absolute Maximum Ratings (Tc = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	900	V	
Collector-emitter voltage		V _{CEO}	800	V	
Emitter-base voltage		V _{EBO}	7	V	
Collector current	DC	IC	3	Α	
	Pulse	I _{CP}	5		
Base current		ΙΒ	1	Α	
Collector power dissipation	Ta = 25°C	PC	2.0	W	
	Tc = 25°C	FC	25		
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	



Weight: 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high

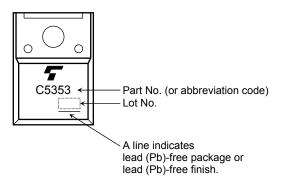
temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

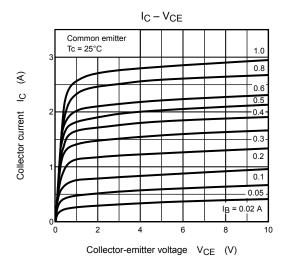
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

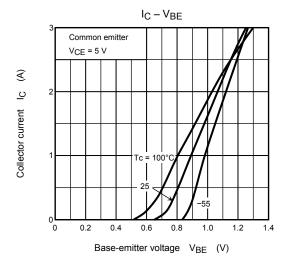
Electrical Characteristics (Tc = 25°C)

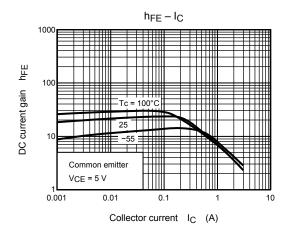
Chara	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off cu	urrent	I _{CBO}	V _{CB} = 720 V, I _E = 0	_	_	100	μΑ
Emitter cut-off cur	rent	I _{EBO}	V _{EB} = 7 V, I _C = 0	_	_	10	μΑ
Collector-base bre	akdown voltage	V (BR) CBO	I _C = 1 mA, I _E = 0	900	_	_	V
Collector-emitter b	oreakdown voltage	V (BR) CEO	I _C = 10 mA, I _B = 0	800	_	_	V
DC current gain		h _{FE (1)}	V _{CE} = 5 V, I _C = 1 mA	CE = 5 V, I _C = 1 mA 10		_	
		h _{FE (2)}	V _{CE} = 5 V, I _C = 0.15 A	15	_	_	
Collector-emitter s	Collector-emitter saturation voltage V _{CE (sat)} I _C = 1.2 A, I _B = 0.24 A		I _C = 1.2 A, I _B = 0.24 A	-	_	1.0	V
Base-emitter saturation voltage		V _{BE} (sat)	I _C = 1.2 A, I _B = 0.24 A	-	_	1.3	V
Switching time	Rise time	t _r	Output Output CC	_	_	0.7	
	Storage time	t _{stg}		_	_	4.0	μs
	Fall time	t _f		-	_	0.5	

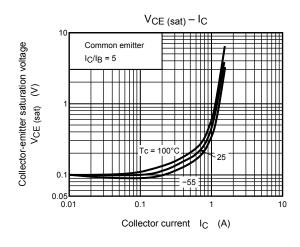
Marking

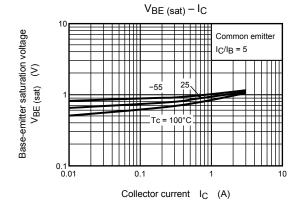


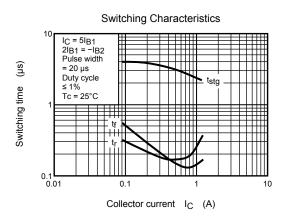




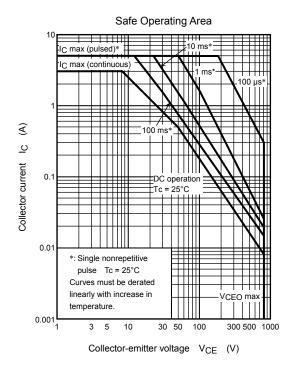


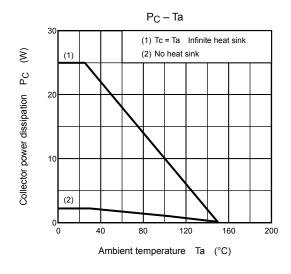






3





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